Mechanical Properties of Chalcogenide Optic Fiber Material Based Tellurium

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Abstract: The variation of microhardness of the samples of the system Te_{80}S_{20-x}B_{x} where (x=0, 2.5, 5 and B=In or As) with the applied test load depends on the sample structure. The sample Te_{80}S_{20} is still elastic until the applied load exceed 2N. The addition of In or As on expense of S, leads to increase the elastic limit. Mayer index (n) of all samples is greater than two. This means that all samples are soft and follow the reverse indentation size effect (RISE). Using indentation induced cracking (IIC) model, ensure the generation of micro-cracks. The behavior of the calculated elastic modulii confirm these results.

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I. Introduction
The chalcogenide glasses are known as optical material around 50 years ago (1), due to its interesting properties such as a wide transparency range, low optical losses, stability to atmospheric moisture (2,3), high non-linearity of optical properties, etc. Due to these reasons, the chalcogenide glasses are first candidate for the production of optic fibers cables (4).

Tellurium-rich alloys are better transparency in the infrared region means these glasses are a good choice for optical devices (5-7). Chalcogenide glasses are insoluble in water, concentrated hydrochloric acid and its softer glass fibers than silica due to the two-fold coordinated chalcogen atoms. They behave as a flexible electron-lattice coupling system when they are subject to exhibit electro-atomic responses (8,9).

The micro-hardness of the glass depends on the atomic radius and the bulk density. The addition of tellurium to chalcogenide glasses improve its mechanical properties due to the increase of atomic mass and atomic radius (10).

The aim of the present research is to study the mechanical properties of the system Te_{80}S_{20-x}B_{x} (x=0, 2.5, 5 and B=In or As). The microhardness as a function of applied test load were recorded. The young modulus, yield strength, stiffness, fracture toughness and brittleness are also determined.

II. Experimental
The chalcogenide samples of the system Te_{80}S_{20-x}B_{x} where (x=0, 2.5, 5 and B=In or As) were prepared by melting quenching technique. Elements Se, S, Te, In& As were weighted and mixed well using the ball milling method for each sample alone. The homogeneous mixture was placed in an evacuated (10^{-5} Pa) and capsulated silica tube. The silica tube containing each sample was heated at fixed temperature for fixed time. The sample Te_{80}S_{20} and the samples contain In on the expense of S were melted at 500C for 8 hours and quenching in ice water. The samples containing As on the expense of S were melted at 800C for 8 hours and then quenching in ice water. The microhardness of samples were investigated using Vicker’s microhardness technique.

III. Result and discussion
The nonlinear variation of microhardness (HV) as a function of the applied test load F(N) for the system Te_{80}S_{20-x}B_{x} where (x=0 ,2.5 ,5) and B= In or As is shown in figure [1]. This behavior can be controlled by the relation (11)

$$HV = 0.1891\frac{F}{d^2}$$

Where HV is Vicker microhardness in GPa, F is applied test load in Newton (N) and d is the arithmetic mean of the two diagonals (mm).

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Fig [1] Vickers microhardness as a function of the applied test load for chalcogenide system Te$_{80}$S$_{20}$-B$_{x}$ [where x=0, 2.5, 5 B=In or As].

Fig [1] shows that, all samples are elastic till the applied test load exceeds the elastic limits. The elastic limit is differ from sample to sample. In case of the sample Te$_{80}$S$_{20}$, the elastic limit is 4N, this is corresponding the microhardness value 4.5GPa. As the applied test load exceeds 4N the sample surface suffers from some distortion around the indentation point. This may be due the generation of micro-cracks.

The factors affecting the microhardness as a function of the test load are interatomic bond length and bond energy strength. The values of possible bond length and bond energy strength were collected and tabulated in table [1]. Table [1] illustrate that the bond length and bond energy strength normally in inverse proportional to each other.

<table>
<thead>
<tr>
<th>S.No.</th>
<th>Bond</th>
<th>Bond energy (KJ/mole)</th>
<th>Bond length (Å)</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>Te-Te</td>
<td>257.6</td>
<td>2.74</td>
</tr>
<tr>
<td>2</td>
<td>Te-S</td>
<td>335</td>
<td>2.405</td>
</tr>
<tr>
<td>3</td>
<td>Te-As</td>
<td>327</td>
<td>2.571</td>
</tr>
<tr>
<td>4</td>
<td>Te-In</td>
<td>215.5</td>
<td>2.81994</td>
</tr>
<tr>
<td>5</td>
<td>As-As</td>
<td>385.8</td>
<td>2.42</td>
</tr>
<tr>
<td>6</td>
<td>In-In</td>
<td>82</td>
<td>3.020</td>
</tr>
<tr>
<td>7</td>
<td>S-S</td>
<td>425.30</td>
<td>2.39</td>
</tr>
<tr>
<td>8</td>
<td>S-In</td>
<td>379.5</td>
<td>2.602</td>
</tr>
<tr>
<td>9</td>
<td>S-As</td>
<td>287.9</td>
<td>2.29</td>
</tr>
</tbody>
</table>

To understand the microhardness behavior well, the obtained results will be analyzed on the light of some models, as follow:

**Mayer's law:**
Mayer's law illustrates the relation holding the applied test load F(N) and diagonal of indentation (d) by equation (12),

\[ F = Ad^n \]

Where \( n \) is Mayer exponent.

The value of \( n \) classify the behavior of microhardness Hv of any sample as follow:

1- If the value of \( n \) is more than the value two (\( n>2 \)) the materials under test is soft and its microhardness follow the reverse indentation size effect (RISE).
2- If the value of \( (n) \) is less than the value two \((n<2)\) the materials under test is hard and its microhardness follow the indentation size effect (ISE).
3- If the value of \( (n) \) is equal to the value two \((n=2)\) the microhardness is independent on the applied load.

This can be carried out by drawing the relation \((\log F)\) vis \((\log d)\) for each sample of the system \(\text{Te}_{80}\text{S}_{20-x}\text{B}_x\) where \(x=0,2.5,5\) and \(B=\text{In or As}\) as in fig [2]. The obtained values of \(n\) are collected in the table [2].

![Graph showing the relationship between log F and log d for different compositions of Te80S20-xBx](image)

**Fig [2] plot Log F and Log d of chalcogenide system Te_{80}S_{20-x}B_x [where x=0, 2.5, 5 B=In or AS].**

<table>
<thead>
<tr>
<th>S.No.</th>
<th>Sample</th>
<th>Meyer's index ((n))</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>Te(<em>{80})S(</em>{20})</td>
<td>2.23</td>
</tr>
<tr>
<td>2</td>
<td>Te(<em>{80})S(</em>{17.5})In(_{2.5})</td>
<td>2.45</td>
</tr>
<tr>
<td>3</td>
<td>Te(<em>{80})S(</em>{17.5})As(_{2.5})</td>
<td>2.26</td>
</tr>
<tr>
<td>4</td>
<td>Te(<em>{80})S(</em>{15})As(_{5})</td>
<td>2.49</td>
</tr>
</tbody>
</table>

Table [2], illustrate that the values of \(n\) are greater than the value two \((n>2)\). This means that, the sample under test is soft and its microhardness follow reverse indentation size effect (RISE). The addition of In or As on the expense of S, leads to increase the elasticity. The elasticity was revealed to be more pronounced as As content reach 5 at %.

**Indentation induced cracking (IIC) model**

Indentation induced cracks IIC model (13) can be explained by drawing \(\log (Hv)\) microhardness as a function of \(\log (F^{1/3}/d^1)\) for the chalcogenide sample of the system \(\text{Te}_{80}\text{S}_{20-x}\text{B}_x\) where \(x=0,2.5,5\) and \(B=\text{In or As}\) shown in figure [3].
Table [3] shows that the values of \(m\) is much less than 0.6. This means that the samples under test behaves as RISE.

Finally, the detected samples cracking were generated when the applied test load exceeds the elastic limit for each sample of the system \(\text{Te}_{80}\text{S}_{20-x}\text{B}_{x}\) where \([(x=0,2.5,5)\) and \(B=\text{In or As}\). This elastic limit can be used as point of control during the manufacture of optic fiber from the chalcogenide system \(\text{Te}_{80}\text{S}_{20-x}\text{B}_{x}\) where \([(x=0,2.5,5)\) and \(B=\text{In or As}\).

The mechanical elastic moduli of the system \(\text{Te}_{80}\text{S}_{20-x}\text{B}_{x}\)
The obtained experimental resulted of the microhardness can be used to investigate the rest of the material mechanical moduli of the system \(\text{Te}_{80}\text{S}_{20-x}\text{B}_{x}\) where \([(x=0,2.5,5)\) and \(B=\text{In or As}\).

1- Young modulus(Y)

Fig [4] shows the linear relation of young modulus as a function of microhardness of the chalcogenide system \(\text{Te}_{80}\text{S}_{20-x}\text{B}_{x}\) where \([(x=0,2.5,5)\) and \(B=\text{In or As}\) (14).
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Fig [4] plot the young modulus $Y$ as a function of microhardness ($H_v$) of the chalcogenide system $\text{Te}_{80} \text{S}_{20-x} \text{B}_x$ [where $x=0, 2.5, 5$ B=In or AS].

Fig [4] proves that, the samples of the system $\text{Te}_{80} \text{S}_{20-x} \text{B}_x$ where [(x=0 ,2.5 ,5) and B= In or As] are elastic. The addition of In or As on the expense of S , leads to increase the elasticity.

2- Yield strength ($Y_s$)

The linear variation of yield strength ($Y_s$) as a function of microhardness ($H_v$) is shown in fig [5] (15)

Fig [5] confirmed the elastic behavior of samples of the system $\text{Te}_{80} \text{S}_{20-x} \text{B}_x$ where [(x=0 ,2.5 ,5) and B= In or As]. Also, fig [5] proves that the addition of In or As leads to increase elasticity of samples.

Fig [5] plot the yield strength ($Y_s$) as a function of microhardness ($H_v$) of the chalcogenide system $\text{Te}_{80} \text{S}_{20-x} \text{B}_x$ [where $x=0, 2.5, 5$ B=In or AS].
3- **Stiffness constant** \((C_{II})\)

Fig [6] shows the relation between stiffness \(C_{II}\) and the microhardness of the samples of the system \(\text{Te}_{80}\text{S}_{20-x}\text{B}_x\) where \([x=0,2.5,5]\) and \(B=\text{In or As}\) (16).

Fig [6] proves that, the stiffness constant increases with microhardness. This means that, the deformation resistance of the sample increases as the applied test load increases.

![Graph showing relation between stiffness and microhardness](image)

**Fig [6]** variation of stiffness \((C_{II})\) and with microhardness of the chalcogenide system \(\text{Se}_{80}\text{S}_{20-x}\text{B}_x\) [where \(x=0,2.5,5\) and \(B=\text{In or As}\)].

4- **Fracture toughness** \((K_F)\)

Fig [7] shows the variation of fracture toughness as a function of microhardness \((Hv)\) of the system \(\text{Te}_{80}\text{S}_{20-x}\text{B}_x\) where \([x=0,2.5,5]\) and \(B=\text{In or As}\) (17).

Fig [7] proves that, the fracture toughness is decreased as microhardness increased. Also, The fracture toughness is decreased after the addition In or As.

![Graph showing relation between fracture toughness and microhardness](image)

**Fig [7]** plot the fracture toughness \((K_F)\) as a function of microhardness \((Hv)\) of the chalcogenide system \(\text{Te}_{80}\text{S}_{20-x}\text{B}_x\) [where \(x=0,2.5,5\) and \(B=\text{In or As}\)].
5- Britteness (B)

Fig [8] shows the brittleness (B) as a function of microhardness (Hv) of the chalcogenide system Te$_{80}$S$_{20}$$_B_x$ [where x=0, 2.5, 5 B=In or AS] (16).

The brittleness of samples was decreased with the increasing of microhardness of the system Te$_{80}$S$_{20}$$_B_x$ [where x=0, 2.5, 5 B=In or AS].

IV. Conclusion

The microhardness of samples of the system Te$_{80}$S$_{20}$$_B_x$ [where x=0, 2.5, 5 B=In or AS] was increased with increasing of the applied test load. The addition of In or AS on the expense of S follow the same behavior. Mayer law proved that all samples of this system are soft and follow reverse indentation size effect (RISE). The indentation induced crack (IIC) model proves the generation of micro-cracks around the indention points. This means that the mechanical resistance of each sample is increased as the applied test load increased. The behavior of the calculated elastic moduli confirm these results.

References

[9]. Amit Kumar, Mouta M.A. Imran, Arvind Sharma, Neeraj Mehta, j m a t e r e r r e s t e c h n o l. 2018;7(1):39–44.